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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	CANbus, I ² C, SCI, SPI, USB OTG
Peripherals	LVD, PWM, WDT
Number of I/O	51
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-QFP
Supplier Device Package	64-QFP (14x14)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mcf51jm32evqh

² Up to 16 pins on Ports A, H, and J are shared with the ColdFire Rapid GPIO module.

1.2 Block Diagram

Figure 1 shows the connections between the MCF51JM128 series pins and modules.

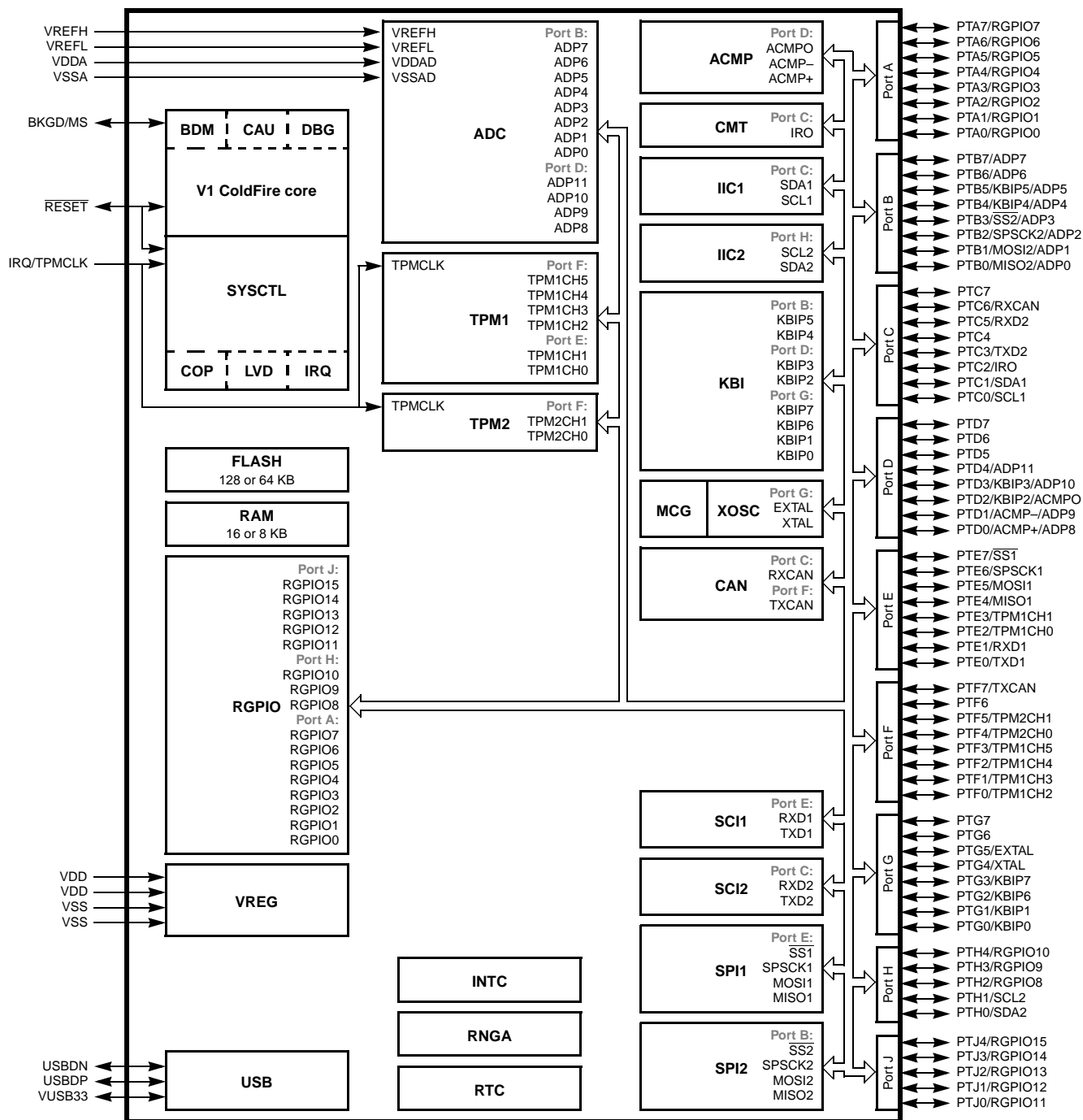


Figure 1. MCF51JM128 Block Diagram

1.3 Features

Table 2 describes the functional units of the MCF51JM128 series.

Table 2. MCF51JM128 Series Functional Units

Unit	Function
CF1CORE (V1 ColdFire core)	Executes programs and interrupt handlers
BDM (background debug module)	Provides a single-pin debugging interface (part of the V1 ColdFire core)
DBG (debug)	Provides debugging and emulation capabilities (part of the V1 ColdFire core)
SYSCCTL (system control)	Provides LVD, COP, external interrupt request, and so on
FLASH (flash memory)	Provides storage for program code and constants
RAM (random-access memory)	Provides storage for program code, constants, and variables
RGPIO (rapid general-purpose input/output)	Allows I/O port access at CPU clock speeds
VREG (voltage regulator)	Controls power management throughout the device
USBOTG (USB On-The-Go)	Supports the USB On-The-Go dual-role controller
ADC (analog-to-digital converter)	Measures analog voltages at up to 12 bits of resolution
TPM1, TPM2 (timer/pulse-width modulators)	Provide a variety of timing-based features
CF1_INTIC (interrupt controller)	Controls and prioritizes all device interrupts
CAU (cryptographic acceleration unit)	Co-processor support for DES, 3DES, AES, MD5, and SHA-1
RNGA (random number generator accelerator)	32-bit random number generator that complies with FIPS-140
RTC (real-time counter)	Provides a constant-time base with optional interrupt
ACMP (analog comparator)	Compares two analog inputs
CMT (carrier modulator timer)	Infrared output used for the Remote Controller
IIC1, IIC2 (inter-integrated circuits)	Supports the standard IIC communications protocol
KBI (keyboard interrupt)	Provides pin interrupt capabilities
MCG (multipurpose clock generator)	Provides clocking options for the device, including a phase-locked loop (PLL) and frequency-locked loop (FLL) for multiplying slower reference clock sources
XOSC (crystal oscillator)	Supports low/high range crystals
CAN (controller area network)	Supports standard CAN communications protocol
SCI1, SCI2 (serial communications interfaces)	Serial communications UARTs that can support RS-232 and LIN protocols
SPI1, SPI2 (serial peripheral interfaces)	Provide a 4-pin synchronous serial interface

MCF51JM128 Family Configurations

- RTC
 - 8-bit modulus counter with binary- or decimal-based prescaler
 - External clock source for precise time base, time-of-day, calendar or task scheduling functions
 - Free running on-chip low power oscillator (1 kHz) for cyclic wake-up without external components
- Carrier modulator timer (CMT)
 - carrier generator, modulator, and transmitter drive the infrared out (IRO) pin
 - operation in independent high/low time control, baseband, FSK, and direct IRO control modes
- Input/Output
 - 66 GPIOs
 - Eight keyboard interrupt pins with selectable polarity
 - Hysteresis and configurable pull-up device on all input pins; configurable slew rate and drive strength on all output pins
 - 16 bits of Rapid GPIO connected to the processor's local 32-bit platform bus with set, clear, and faster toggle functionality

1.4 Part Numbers

Table 3. Orderable Part Number Summary

Freescall Part Number	Description	Flash / SRAM (KB)	Package	Temperature
MCF51JM128EVVK	MCF51JM128 ColdFire Microcontroller with CAU and RAGA Enabled	128 / 16	80 LQFP	–40 to +105 °C
MCF51JM128VVK	MCF51JM128 ColdFire Microcontroller	128 / 16	80 LQFP	–40 to +105 °C
MCF51JM128EVLH	MCF51JM128 ColdFire Microcontroller with CAU and RAGA Enabled	128 / 16	64 LQFP	–40 to +105 °C
MCF51JM128VLH	MCF51JM128 ColdFire Microcontroller	128 / 16	64 LQFP	–40 to +105 °C
MCF51JM128EVQH	MCF51JM128 ColdFire Microcontroller with CAU and RAGA Enabled	128 / 16	64 QFP	–40 to +105 °C
MCF51JM128VQH	MCF51JM128 ColdFire Microcontroller	128 / 16	64 QFP	–40 to +105 °C
MCF51JM128EVLV	MCF51JM128 ColdFire Microcontroller with CAU and RAGA Enabled	128 / 16	44 LQFP	–40 to +105 °C
MCF51JM128VLV	MCF51JM128 ColdFire Microcontroller	128 / 16	44 LQFP	–40 to +105 °C
MCF51JM64EVVK	MCF51JM64 ColdFire Microcontroller with CAU and RAGA Enabled	64 / 16	80 LQFP	–40 to +105 °C
MCF51JM64VVK	MCF51JM64 ColdFire Microcontroller	64 / 16	80 LQFP	–40 to +105 °C
MCF51JM64EVLH	MCF51JM64 ColdFire Microcontroller with CAU and RAGA Enabled	64 / 16	64 LQFP	–40 to +105 °C
MCF51JM64VLH	MCF51JM64 ColdFire Microcontroller	64 / 16	64 LQFP	–40 to +105 °C
MCF51JM64EVQH	MCF51JM64 ColdFire Microcontroller with CAU and RAGA Enabled	64 / 16	64 QFP	–40 to +105 °C
MCF51JM64VQH	MCF51JM64 ColdFire Microcontroller	64 / 16	64 QFP	–40 to +105 °C

Table 3. Orderable Part Number Summary (continued)

MCF51JM64EVLD	MCF51JM64 ColdFire Microcontroller with CAU and RNGA Enabled	64 / 16	44 LQFP	–40 to +105 °C
MCF51JM64VLD	MCF51JM64 ColdFire Microcontroller	64 / 16	44 LQFP	–40 to +105 °C
MCF51JM32EVLK	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	80 LQFP	–40 to +105 °C
MCF51JM32VLK	MCF51JM32 ColdFire Microcontroller	32 / 16	80 LQFP	–40 to +105 °C
MCF51JM32EVLH	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	64 LQFP	–40 to +105 °C
MCF51JM32VLH	MCF51JM32 ColdFire Microcontroller	32 / 16	64 LQFP	–40 to +105 °C
MCF51JM32EVQH	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	64 QFP	–40 to +105 °C
MCF51JM32VQH	MCF51JM32 ColdFire Microcontroller	32 / 16	64 QFP	–40 to +105 °C
MCF51JM32EVLD	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	44 LQFP	–40 to +105 °C
MCF51JM32VLD	MCF51JM32 ColdFire Microcontroller	32 / 16	44 LQFP	–40 to +105 °C

Figure 3 shows the pinout of the 64-pin LQFP and QFP.

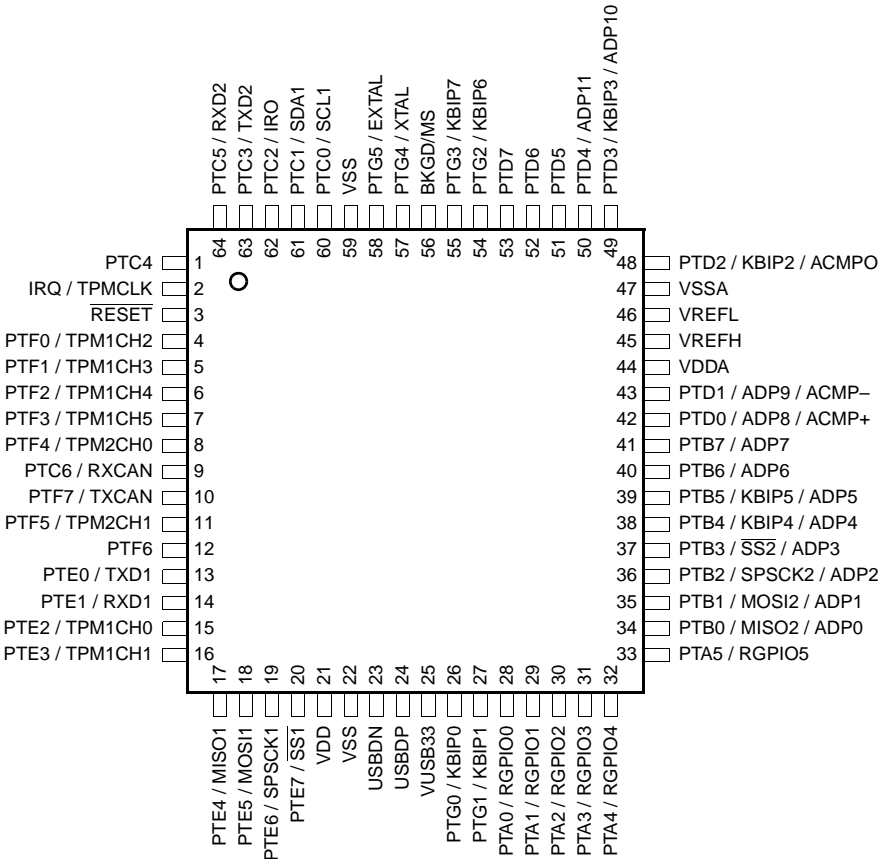


Figure 3. 64-pin QFP and LQFP

Table 6. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	−0.3 to + 5.8	V
Input voltage	V_{In}	− 0.3 to $V_{DD} + 0.3$	V
Instantaneous maximum current Single pin limit (applies to all port pins) ^{1, 2, 3}	I_D	± 25	mA
Maximum current into V_{DD}	I_{DD}	120	mA
Storage temperature	T_{stg}	−55 to +150	°C
Maximum junction temperature	T_J	150	°C

¹ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.

² All functional non-supply pins are internally clamped to V_{SS} and V_{DD} .

³ Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load shunt current is greater than maximum injection current. This is the greatest risk when the MCU is not consuming power. Examples: if no system clock is present or if the clock rate is low, which would reduce overall power consumption.

2.3 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} is small.

Table 7. Thermal Characteristics

Rating	Symbol	Value	Unit
Operating temperature range (packaged)	T_A	−40 to +105	°C
Thermal resistance ^{1,2,3,4}			
80-pin LQFP			
	1s	52	
	2s2p	40	
64-pin LQFP			
	1s	65	
	2s2p	47	
64-pin QFP			
	1s	54	
	2s2p	40	
44-pin LQFP			
	1s	69	
	2s2p	48	

¹ Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

² Junction to Ambient Natural Convection

Table 9. ESD and Latch-Up Protection Characteristics

Num	Rating	Symbol	Min	Max	Unit
1	Human Body Model (HBM)	V_{HBM}	+/- 2000	—	V
2	Charge Device Model (CDM)	V_{CDM}	+/- 500	—	V
3	Latch-up Current at $T_A = 105^{\circ}\text{C}$	I_{LAT}	+/- 100	—	mA

2.5 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 10. DC Characteristics

Num	C	Parameter	Symbol	Min	Typ ¹	Max	Unit
1		Operating voltage ²		2.7	—	5.5	V
2	P	Output high voltage — Low Drive (PTxDSn = 0) 5 V, $I_{Load} = -4$ mA 3 V, $I_{Load} = -2$ mA 5 V, $I_{Load} = -2$ mA 3 V, $I_{Load} = -1$ mA	V_{OH}	$V_{DD} - 1.5$ $V_{DD} - 1.5$ $V_{DD} - 0.8$ $V_{DD} - 0.8$	— — — —	— — — —	V
		Output high voltage — High Drive (PTxDSn = 1) 5 V, $I_{Load} = -15$ mA 3 V, $I_{Load} = -8$ mA 5 V, $I_{Load} = -8$ mA 3 V, $I_{Load} = -4$ mA		$V_{DD} - 1.5$ $V_{DD} - 1.5$ $V_{DD} - 0.8$ $V_{DD} - 0.8$	— — — —	— — — —	
3	P	Output low voltage — Low Drive (PTxDSn = 0) 5 V, $I_{Load} = 4$ mA 3 V, $I_{Load} = 2$ mA 5 V, $I_{Load} = 2$ mA 3 V, $I_{Load} = 1$ mA	V_{OL}		— — — —	1.5 1.5 0.8 0.8	V
		Output low voltage — High Drive (PTxDSn = 1) 5 V, $I_{Load} = 15$ mA 3 V, $I_{Load} = 8$ mA 5 V, $I_{Load} = 8$ mA 3 V, $I_{Load} = 4$ mA			— — — —	1.5 1.5 0.8 0.8	
4	P	Output high current — Max total I_{OH} for all ports 5V 3V	I_{OHT}	— —	— —	100 60	mA
5	P	Output low current — Max total I_{OL} for all ports 5V 3V	I_{OLT}	— —	— —	100 60	mA
6	P	Input high voltage; all digital inputs	V_{IH}				V
		$V_{DD} = 5V$ $V_{DD} = 3V$		3.25 2.10	— —	— —	

Preliminary Electrical Characteristics

- ¹ Typical values are based on characterization data at 25°C unless otherwise stated.
- ² Operating voltage with USB enabled can be found in Section 2.14, "USB Electricals."
- ³ Measured with $V_{In} = V_{DD}$ or V_{SS} .
- ⁴ Measured with $V_{In} = V_{SS}$.
- ⁵ Measured with $V_{In} = V_{DD}$.
- ⁶ This is the voltage below which the contents of RAM are not guaranteed to be maintained.

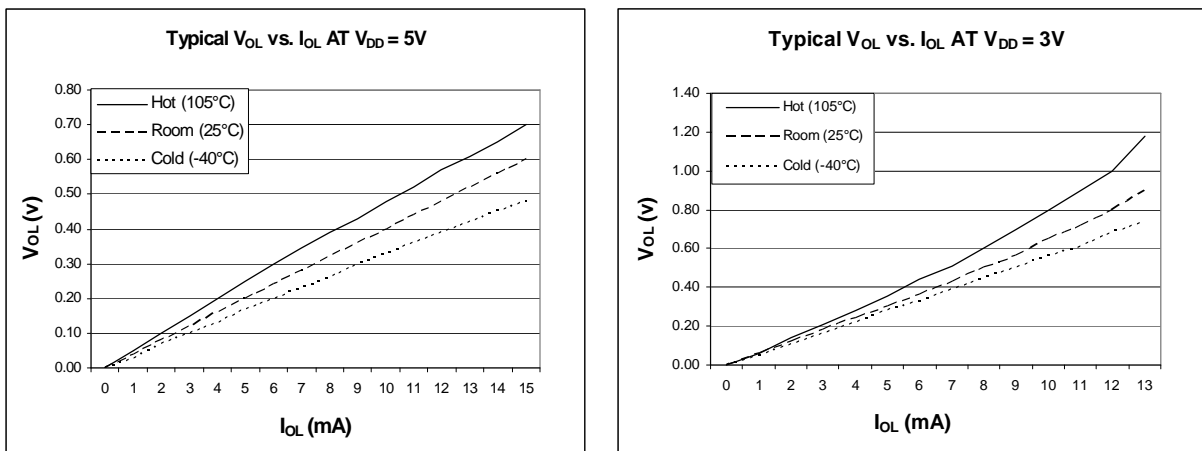


Figure 5. Typical Low-side Drive (sink) characteristics – High Drive (PTxDSn = 1)

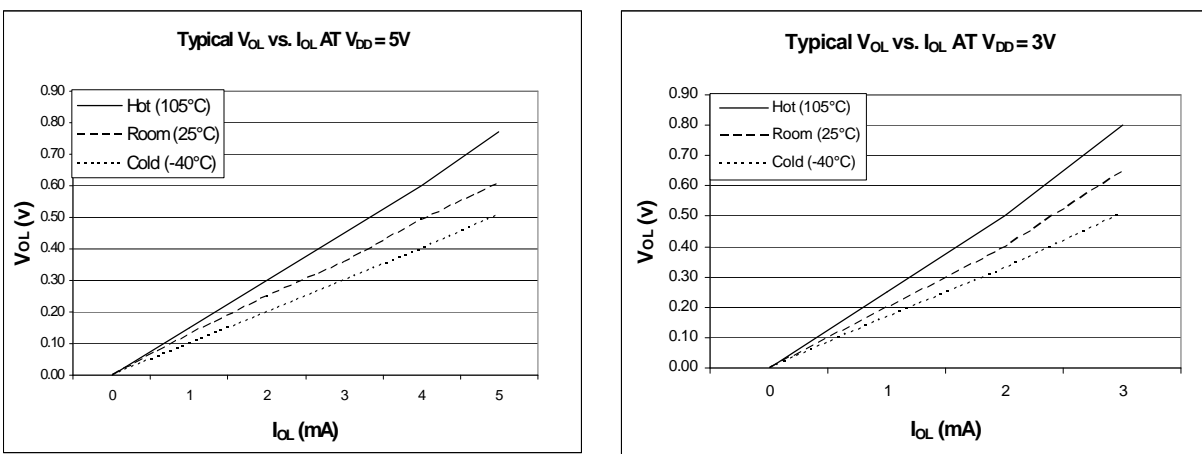


Figure 6. Typical Low-side Drive (sink) characteristics – Low Drive (PTxDSn = 0)

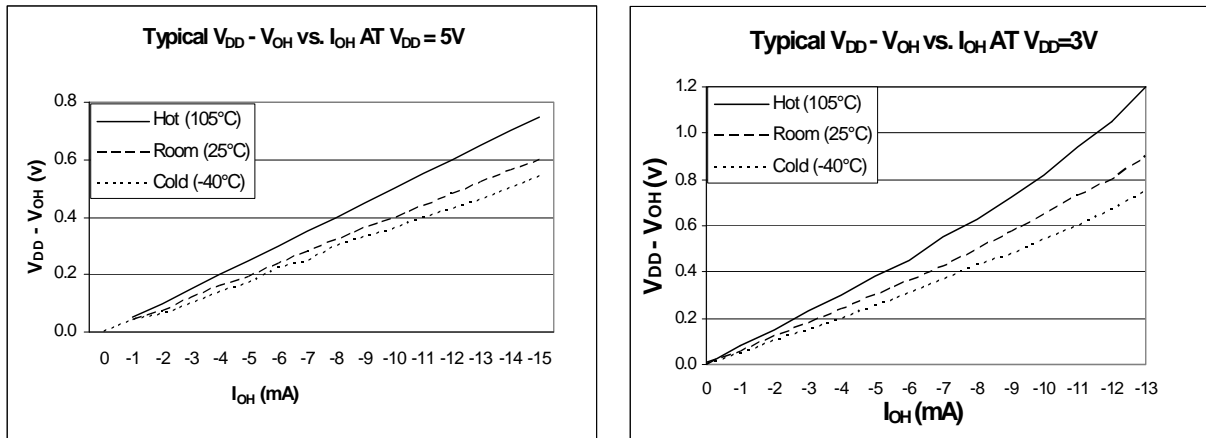


Figure 7. Typical High-side Drive (source) characteristics – High Drive (PTxDSn = 1)

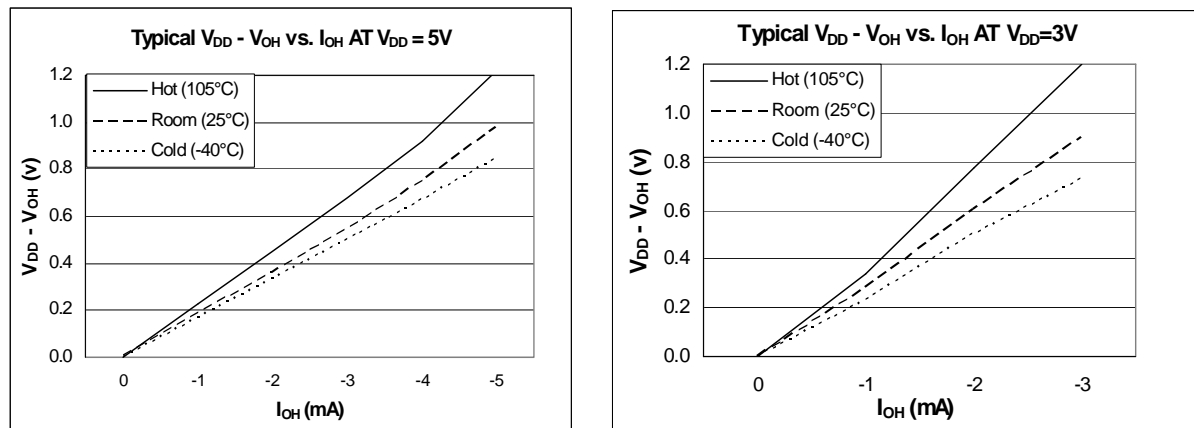


Figure 8. Typical High-side Drive (source) characteristics – Low Drive (PTxDSn = 0)

2.6 Supply Current Characteristics

Table 11. Supply Current Characteristics

Num	C	Parameter	Symbol	V_{DD} (V)	Typical ¹	Max ²	Unit
1	C	Run supply current ³ measured at (CPU clock = 2 MHz, $f_{Bus} = 1$ MHz)	R_{IDD}	5	4.0	7	mA
				3	4.0	7	
2	P	Run supply current ³ measured at (CPU clock = 16 MHz, $f_{Bus} = 8$ MHz)		5	19	30	mA
				3	18.7	30	
3	C	Run supply current ³ measured at (CPU clock = 48 MHz, $f_{Bus} = 24$ MHz)		5	45	70	mA
				3	44	70	

2.7 Analog Comparator (ACMP) Electricals

Table 12. Analog Comparator Electrical Specifications

Num	C	Rating	Symbol	Min	Typical	Max	Unit
1		Supply voltage	V_{DD}	2.7	—	5.5	V
2		Supply current (active)	I_{DDAC}	—	20	35	μA
3		Analog input voltage	V_{AIN}	$V_{SS} - 0.3$	—	V_{DD}	V
4		Analog input offset voltage	V_{AIO}		20	40	mV
5		Analog Comparator hysteresis	V_H	3.0	6.0	20.0	mV
6		Analog input leakage current	I_{ALKG}	--	--	1.0	μA
7		Analog Comparator initialization delay	t_{AINIT}	—	—	1.0	μs
8		Bandgap Voltage Reference Factory trimmed at $V_{DD} = 3.0$ V, Temp = 25°C	V_{BG}	1.19	1.20	1.21	V

2.8 ADC Characteristics

Table 13. 5 Volt 12-bit ADC Operating Conditions

Characteristic	Conditions	Symb	Min	Typ ¹	Max	Unit	Comment
Supply voltage	Absolute	V_{DDA}	2.7	—	5.5	V	
	Delta to V_{DD} ($V_{DD} - V_{DDA}$) ²	ΔV_{DDA}	-100	0	+100	mV	
Ground voltage	Delta to V_{SS} ($V_{SS} - V_{SSA}$) ²	ΔV_{SSA}	-100	0	+100	mV	
Ref Voltage High		V_{REFH}	2.7	V_{DDA}	V_{DDA}	V	
Ref Voltage Low		V_{REFL}	V_{SSA}	V_{SSA}	V_{SSA}	V	
Input Voltage		V_{ADIN}	V_{REFL}	—	V_{REFH}	V	
Input Capacitance		C_{ADIN}	—	4.5	5.5	pF	
Input Resistance		R_{ADIN}	—	3	5	k Ω	
Analog Source Resistance	12 bit mode $f_{ADCK} > 4$ MHz $f_{ADCK} < 4$ MHz	R_{AS}	— —	— —	2 5	k Ω	External to MCU
	10 bit mode $f_{ADCK} > 4$ MHz $f_{ADCK} < 4$ MHz		— —	— —	5 10		
	8 bit mode (all valid f_{ADCK})		—	—	10		
ADC Conversion Clock Freq.	High Speed (ADLPC=0)	f_{ADCK}	0.4	—	8.0	MHz	
	Low Power (ADLPC=1)		0.4	—	4.0		

¹ Typical values assume $V_{DDA} = 5.0$ V, Temp = 25°C, $f_{ADCK} = 1.0$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

² DC potential difference.

Table 14. 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Conversion Time (Including sample time)	Short Sample (ADLSMP=0)	T	t_{ADC}	—	20	—	ADCK cycles	See Table 9 for conversion time variances
	Long Sample (ADLSMP=1)			—	40	—		
Sample Time	Short Sample (ADLSMP=0)	T	t_{ADS}	—	3.5	—	ADCK cycles	
	Long Sample (ADLSMP=1)			—	23.5	—		
Total Unadjusted Error	12 bit mode	T	E_{TUE}	—	± 3.0	—	LSB ²	Includes quantization
	10 bit mode	P		—	± 1	± 2.5		
	8 bit mode	T		—	± 0.5	± 1.0		
Differential Non-Linearity	12 bit mode	T	DNL	—	± 1.75	—	LSB ²	
	10 bit mode ³	P		—	± 0.5	± 1.0		
	8 bit mode ³	T		—	± 0.3	± 0.5		
Integral Non-Linearity	12 bit mode	T	INL	—	± 1.5	—	LSB ²	
	10 bit mode	T		—	± 0.5	± 1.0		
	8 bit mode	T		—	± 0.3	± 0.5		
Zero-Scale Error	12 bit mode	T	E_{ZS}	—	± 1.5	—	LSB ²	$V_{ADIN} = V_{SSAD}$
	10 bit mode	P		—	± 0.5	± 1.5		
	8 bit mode	T		—	± 0.5	± 0.5		
Full-Scale Error	12 bit mode	T	E_{FS}	—	± 1	—	LSB ²	$V_{ADIN} = V_{DDAD}$
	10 bit mode	T		—	± 0.5	± 1		
	8 bit mode	T		—	± 0.5	± 0.5		
Quantization Error	12 bit mode	D	E_Q	—	-1 to 0	—	LSB ²	
	10 bit mode			—	—	± 0.5		
	8 bit mode			—	—	± 0.5		
Input Leakage Error	12 bit mode	D	E_{IL}	—	± 1	—	LSB ²	Pad leakage ⁴ * R_{AS}
	10 bit mode			—	± 0.2	± 2.5		
	8 bit mode			—	± 0.1	± 1		
Temp Sensor Voltage	25°C	D	V_{TEMP25}	—	1.396	—	V	
Temp Sensor Slope	-40°C - 25°C	D	m	—	3.266	—	mV/°C	
	25°C - 125°C			—	3.638	—		

¹ Typical values assume $V_{DDA} = 5.0V$, Temp = 25°C, $f_{ADCK} = 1.0MHz$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² 1 LSB = $(V_{REFH} - V_{REFL})/2^N$

³ Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

⁴ Based on input pad leakage current. Refer to pad electricals.

2.9 External Oscillator (XOSC) Characteristics

Table 15. Oscillator Electrical Specifications (Temperature Range = –40 to 105°C Ambient)

Num	C	Rating	Symbol	Min	Typ ¹	Max	Unit
1		Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) <ul style="list-style-type: none"> Low range (RANGE = 0) High range (RANGE = 1) FEE or FBE mode ² High range (RANGE = 1) PEE or PBE mode ³ High range (RANGE = 1, HGO = 1) BLPE mode High range (RANGE = 1, HGO = 0) BLPE mode 	f_{lo} f_{hi-ll} f_{hi-pll} f_{hi-hgo} f_{hi-lp}	32 1 1 1 1	— — — — —	38.4 5 16 16 8	kHz MHz MHz MHz MHz
2		Load capacitors	C_1 C_2	See crystal or resonator manufacturer's recommendation.			
3		Feedback resistor <ul style="list-style-type: none"> Low range (32 kHz to 38.4 kHz) High range (1 MHz to 16 MHz) 	R_F		10 1		MΩ MΩ
4	—	Series resistor <ul style="list-style-type: none"> Low range, low gain (RANGE = 0, HGO = 0) Low range, high gain (RANGE = 0, HGO = 1) High range, low gain (RANGE = 1, HGO = 0) High range, high gain (RANGE = 1, HGO = 1) 	R_S	— — — — — — —	0 100 0 0 0 0 0	— — — 0 10 20	kΩ
5	T	Crystal start-up time ⁴ <ul style="list-style-type: none"> Low range, low gain (RANGE = 0, HGO = 0) Low range, high gain (RANGE = 0, HGO = 1) High range, low gain (RANGE = 1, HGO = 0) ⁵ High range, high gain (RANGE = 1, HGO = 1) ⁵ 	$t_{CSTL-LP}$ $t_{CSTL-HGO}$ $t_{CSTH-LP}$ $t_{CSTH-HGO}$	— — — —	200 400 5 15	— — — —	ms
6	T	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) <ul style="list-style-type: none"> FEE or FBE mode ² PEE or PBE mode ³ BLPE mode 	f_{extal}	0.03125 1 0	— — —	5 16 40	MHz MHz MHz

¹ Data in Typical column was characterized at 5.0 V, 25°C or is typical recommended value.

² When MCG is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.

³ When MCG is configured for PEE or PBE mode, input clock source must be divisible using RDIV to within the range of 1 MHz to 2 MHz.

⁴ This parameter is characterized and not tested on each device. Proper PC board-layout procedures must be followed to achieve specifications.

⁵ 4 MHz crystal

2.10 MCG Specifications

Table 16. MCG Frequency Specifications (Temperature Range = –40 to 125°C Ambient)

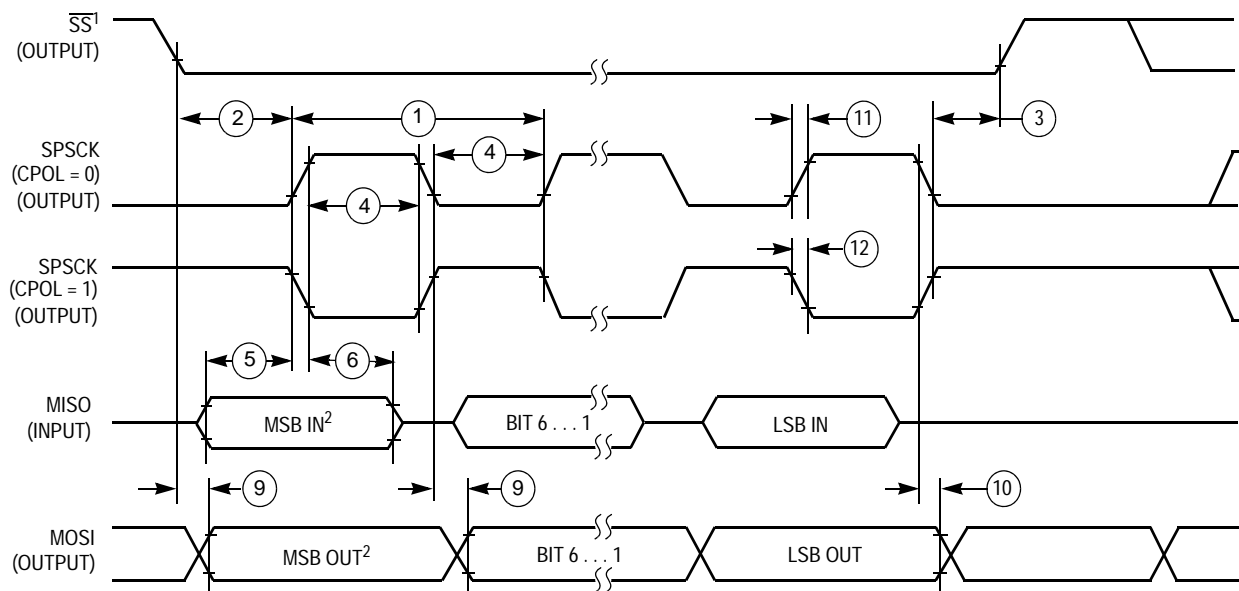
Num	C	Rating		Symbol	Min	Typical ¹	Max	Unit
1	P	Internal reference frequency - factory trimmed at V _{DD} = 5 V and temperature = 25 °C		f _{int_ft}	—	32.768	—	kHz
2	P	Average internal reference frequency – untrimmed		f _{int_ut}	31.25	—	39.0625	kHz
3	T	Internal reference startup time		t _{irefst}	—	60	100	μs
4	P	DCO output frequency range - untrimmed ²	Low range (DRS=00)	f _{dco_ut}	16	—	20	MHz
	P		Mid range (DRS=01)		32	—	40	
	P		High range (DRS=10)		48	—	60	
5	P	DCO output frequency ² Reference = 32768Hz and DMX32 = 1	Low range (DRS=00)	f _{dco_DMx32}	—	19.92	—	MHz
	P		Mid range (DRS=01)		—	39.85	—	
	P		High range (DRS=10)		—	59.77	—	
6	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (using FTRIM)		Δf _{dco_res_t}	—	±0.1	±0.2	%f _{dco}
7	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (not using FTRIM)		Δf _{dco_res_t}	—	±0.2	±0.4	%f _{dco}
8	D	Total deviation of trimmed DCO output frequency over voltage and temperature		Δf _{dco_t}	—	0.5 –1.0	±2	%f _{dco}
9	D	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0 – 70 °C		Δf _{dco_t}	—	±0.5	±1	%f _{dco}
10	D	FLL acquisition time ³		t _{fill_acquire}	—	—	1	ms
11	D	PLL acquisition time ⁴		t _{pll_acquire}	—	—	1	ms
12	D	Long term Jitter of DCO output clock (averaged over 2ms interval) ⁵		C _{Jitter}	—	0.02	0.2	%f _{dco}
13	D	VCO operating frequency		f _{vco}	7.0	—	55.0	MHz
14	D	Jitter of PLL output clock measured over 625 ns ⁶		f _{pll_jitter_625ns}	—	0.566 ⁵	—	%f _{pll}
15	D	Lock entry frequency tolerance ⁷		D _{lock}	±1.49	—	±2.98	%
16	D	Lock exit frequency tolerance ⁸		D _{unl}	±4.47	—	±5.97	%
17	D	Lock time — FLL		t _{fill_lock}	—	—	t _{fill_acquire} + 1075(1/f _{int_t})	s
18	D	Lock time — PLL		t _{pll_lock}	—	—	t _{pll_acquire} + 1075(1/f _{pll_ref})	s
19	D	Loss of external clock minimum frequency – RANGE = 0		f _{loc_low}	(3/5) x f _{int}	—	—	kHz

¹ Data in Typical column was characterized at 5.0 V, 25C or is typical recommended value

² The resulting bus clock frequency should not exceed the maximum specified bus clock frequency of the device.

³ This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

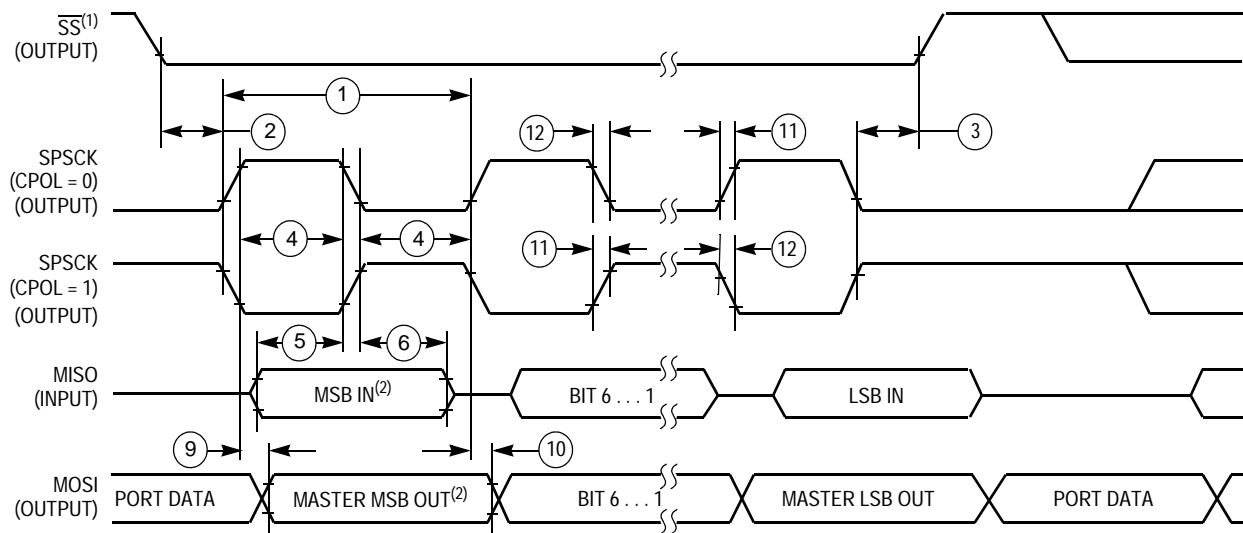
⁴ This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.



NOTES:

1. \overline{SS} output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

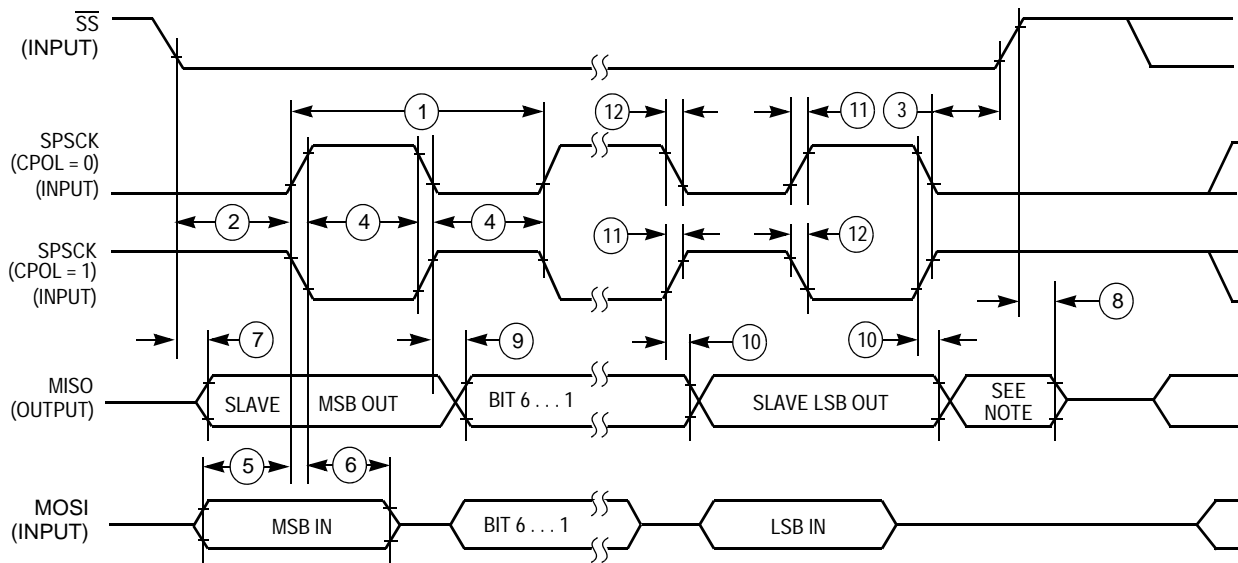
Figure 14. SPI Master Timing (CPHA = 0)



NOTES:

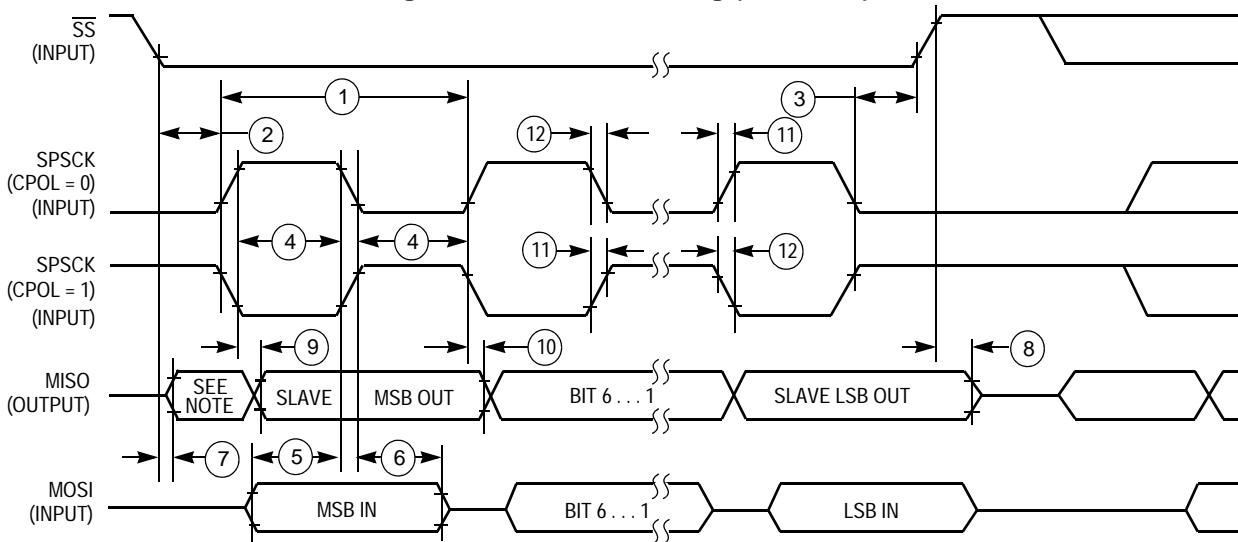
1. \overline{SS} output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 15. SPI Master Timing (CPHA = 1)



NOTE:
1. Not defined but normally MSB of character just received

Figure 16. SPI Slave Timing (CPHA = 0)



NOTE:
1. Not defined but normally LSB of character just received

Figure 17. SPI Slave Timing (CPHA = 1)

Table 22. Internal USB 3.3V Voltage Regulator Characteristics

	Symbol	Unit	Min	Typ	Max
Regulator operating voltage	V_{regin}	V	3.9	—	5.5
Vreg output	V_{regout}	V	3	3.3	3.6
Vusb33 input with internal Vreg disabled	V_{usb33in}	V	3	3.3	3.6
VREG Quiescent Current	I_{VRQ}	mA	—	0.5	—

2.15 EMC Performance

Electromagnetic compatibility (EMC) performance is highly dependant on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as AN2321, AN1050, AN1263, AN2764, and AN1259 for advice and guidance specifically targeted at optimizing EMC performance.

2.15.1 Radiated Emissions

Microcontroller radiated RF emissions are measured from 150 kHz to 1 GHz using the TEM/GTEM Cell method in accordance with the IEC 61967-2 and SAE J1752/3 standards. The measurement is performed with the microcontroller installed on a custom EMC evaluation board while running specialized EMC test software. The radiated emissions from the microcontroller are measured in a TEM cell in two package orientations (North and East). For more detailed information concerning the evaluation results, conditions and setup, please refer to the EMC Evaluation Report for this device.

3.2 64-pin LQFP

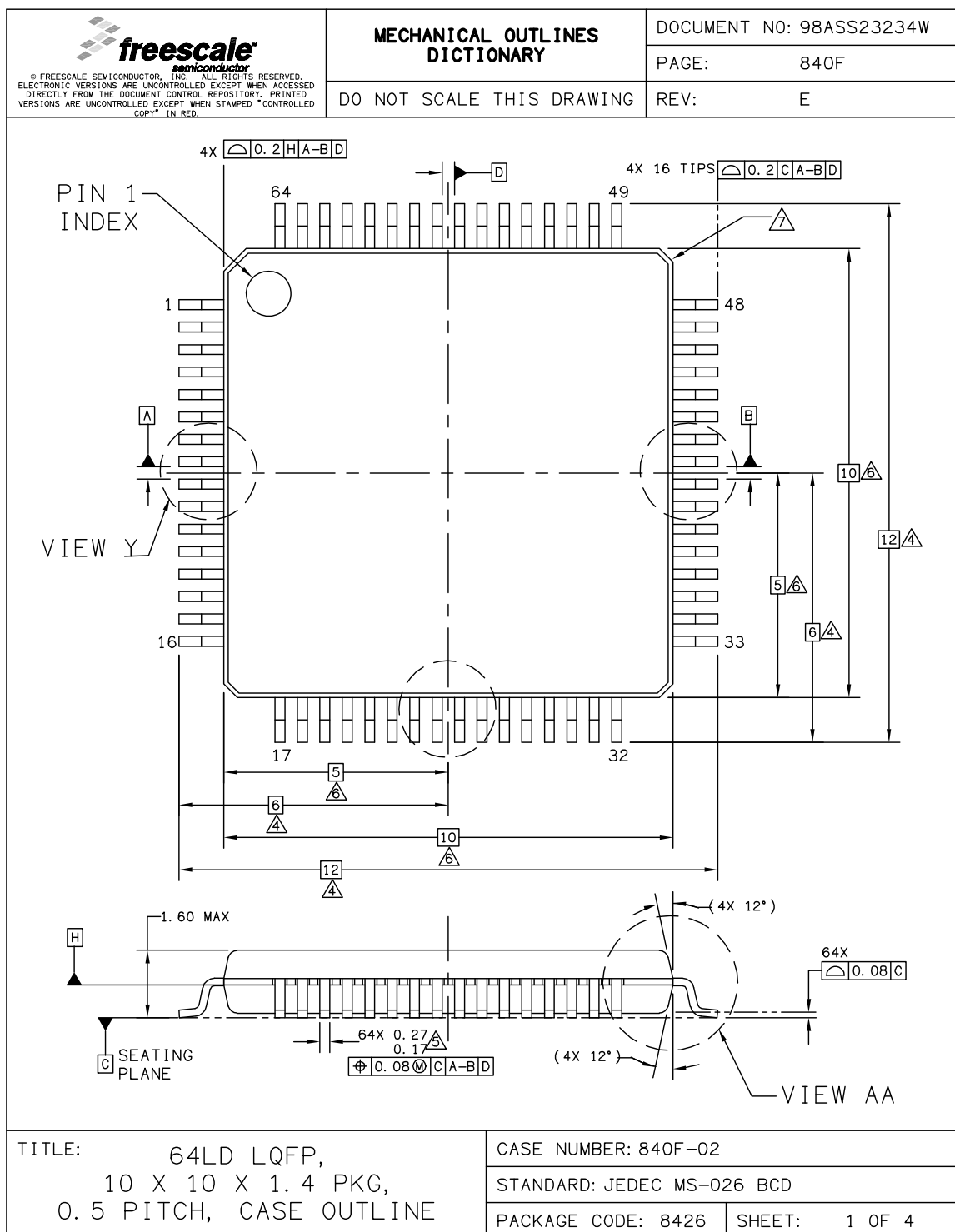


Figure 21. 64-pin LQFP Diagram - I


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			PAGE:	840F
	DO NOT SCALE THIS DRAWING		REV:	E
<p>NOTES:</p> <p>1. DIMENSIONS ARE IN MILLIMETERS.</p> <p>2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.</p> <p>3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.</p> <p>④ DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.</p> <p>⑤ THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.</p> <p>⑥ THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.</p> <p>⑦ EXACT SHAPE OF EACH CORNER IS OPTIONAL.</p> <p>⑧ THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.</p>				
TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE		CASE NUMBER: 840F-02		
		STANDARD: JEDEC MS-026 BCD		
		PACKAGE CODE: 8426	SHEET:	3

Figure 23. 64-pin LQFP Diagram - III

3.3 64-pin QFP

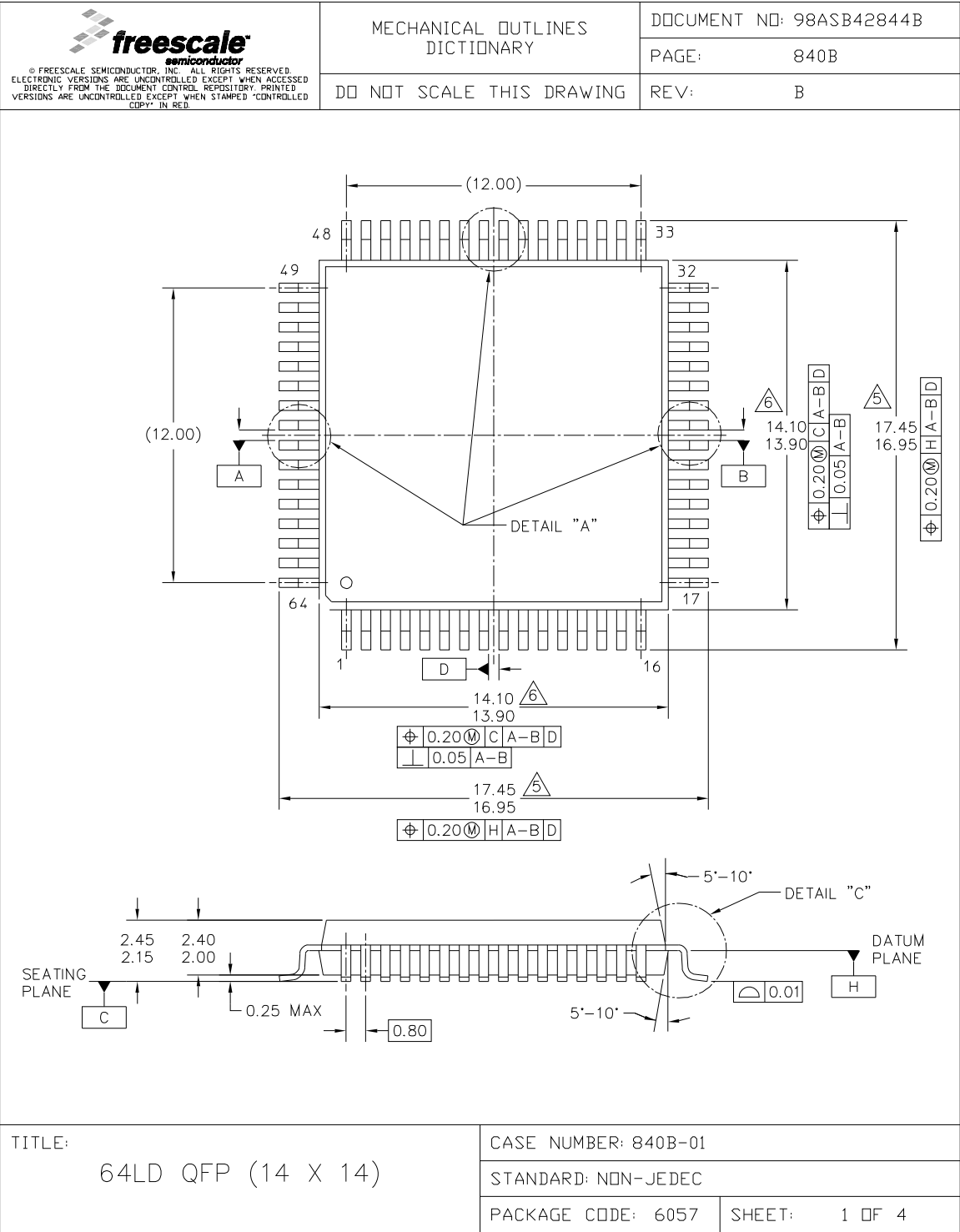


Figure 24. 64-pin QFP Diagram - I

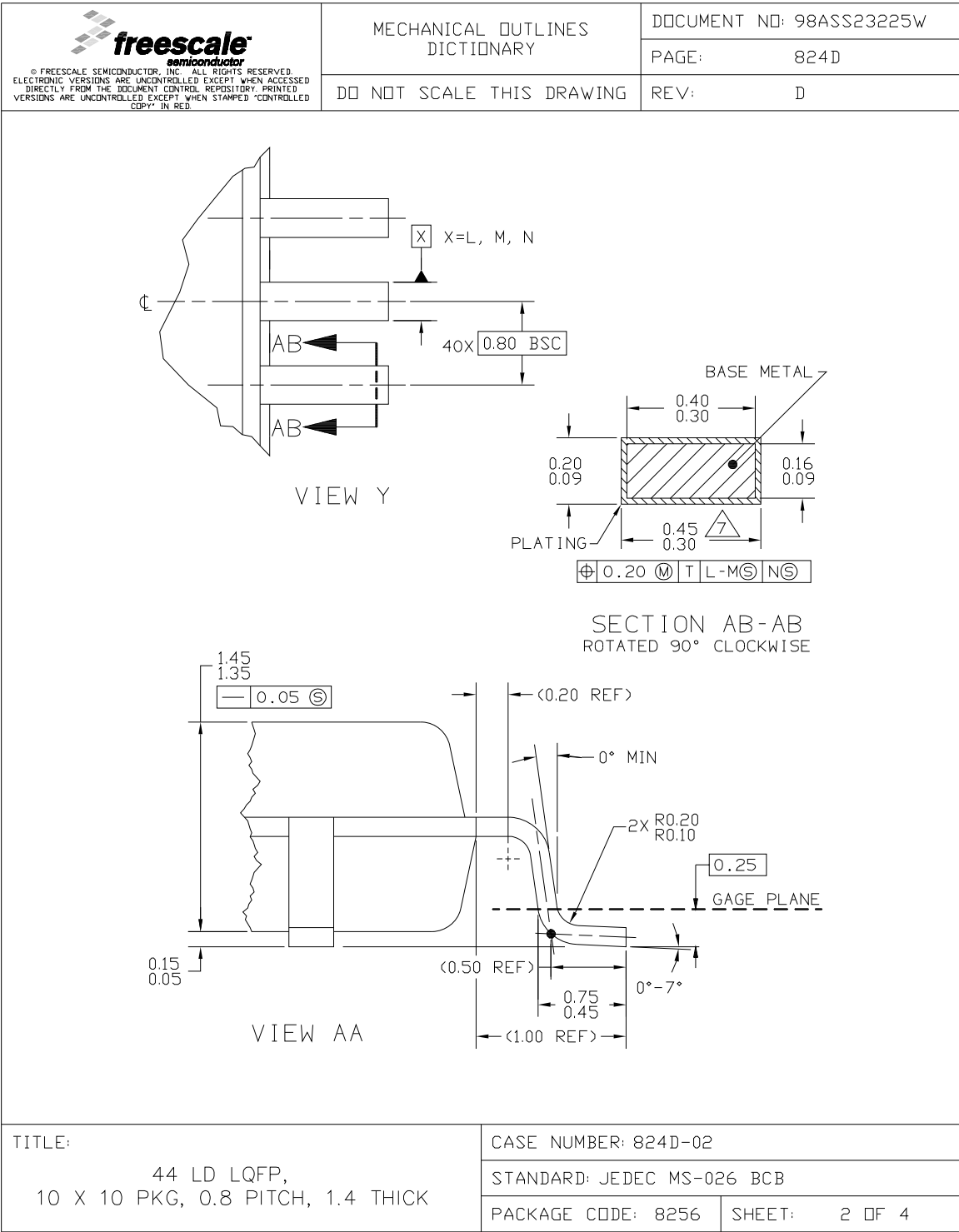


Figure 28. 44-pin LQFP Diagram - II